TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSVII)

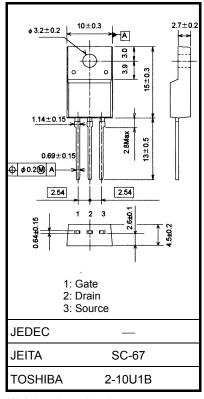
# TK5A50D

#### Switching Regulator Applications

- Low drain-source ON-resistance: R<sub>DS</sub> (ON) = 1.3 Ω (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 3.0 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS}$  = 10  $\mu$ A (max) (V<sub>DS</sub> = 500 V)
- Enhancement mode:  $V_{th}$  = 2.4 to 4.4 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

| Characteristics                               |                              | Symbol           | Rating     | Unit |  |
|---|------------------------------|------------------|------------|------|--|
| Drain-source voltage                          |                              | V <sub>DSS</sub> | 500        | V    |  |
| Gate-source voltage                           |                              | V <sub>GSS</sub> | ±30        | V    |  |
| Drain current                                 | DC (Note 1)                  | Ι <sub>D</sub>   | 5          |      |  |
|   | Pulse (t = 1 ms)<br>(Note 1) | I <sub>DP</sub>  | 20         | A    |  |
| Drain power dissipation (Tc = $25^{\circ}$ C) |                              | PD               | 35         | W    |  |
| Single pulse avalanche energy<br>(Note 2)     |                              | E <sub>AS</sub>  | 150        | mJ   |  |
| Avalanche current                             |                              | I <sub>AR</sub>  | 5          | А    |  |
| Repetitive avalanche energy (Note 3)          |                              | E <sub>AR</sub>  | 3.5        | mJ   |  |
| Channel temperature                           |                              | T <sub>ch</sub>  | 150        | °C   |  |
| Storage temperature range                     |                              | T <sub>stg</sub> | -55 to 150 | °C   |  |

#### Absolute Maximum Ratings (Ta = 25°C)



Weight : 1.7 g (typ.)

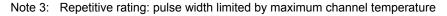
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

| Characteristics                        | Symbol                 | Max  | Unit |
|--|------------------------|------|------|
| Thermal resistance, channel to case    | R <sub>th (ch-c)</sub> | 3.57 | °C/W |
| Thermal resistance, channel to ambient | R <sub>th (ch-a)</sub> | 62.5 | °C/W |

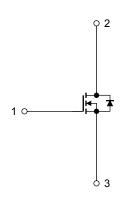
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 10.2 mH,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = 5 A



This transistor is an electrostatic-sensitive device. Handle with care.

Internal Connection



Start of commercial production 2008-09

Unit: mm

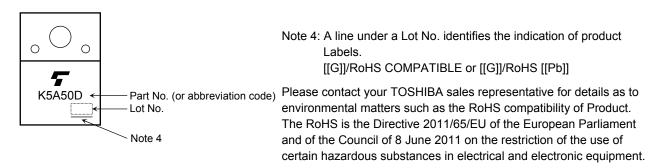
**Electrical Characteristics (Ta = 25°C)** 

| Char                         | acteristics    | Symbol               | Test Condition   | Min | Тур. | Max | Unit |
|------------------------------|----------------|----------------------|--|-----|------|-----|------|
| Gate leakage current         |                | I <sub>GSS</sub>     | $V_{GS}=\pm 30~V,~V_{DS}=0~V$  | _   |      | ±1  | μA   |
| Drain cut-off current        |                | IDSS                 | $V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$   | _   |      | 10  | μA   |
| Drain-source bre             | akdown voltage | V (BR) DSS           | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$  | 500 |      | _   | V    |
| Gate threshold v             | oltage         | V <sub>th</sub>      | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$  | 2.4 |      | 4.4 | V    |
| Drain-source ON              | l-resistance   | R <sub>DS (ON)</sub> | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.5 \text{ A}$   | _   | 1.3  | 1.5 | Ω    |
| Forward transfer             | admittance     | Y <sub>fs</sub>      | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 2.5 \text{ A}$   | 0.8 | 3.0  | _   | S    |
| Input capacitance            |                | C <sub>iss</sub>     |  | —   | 490  | _   |      |
| Reverse transfer capacitance |                | C <sub>rss</sub>     | V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz   | —   | 3    | —   | pF   |
| Output capacitance           |                | C <sub>oss</sub>     |  |     | 55   |     |      |
| Switching time               | Rise time      | tr                   | $V_{GS}^{0} \vee \downarrow $ |     | 18   | _   |      |
|                              | Turn-on time   | t <sub>on</sub>      |  |     | 40   |     | . ns |
|                              | Fall time      | t <sub>f</sub>       |  |     | 8    | _   |      |
|                              | Turn-off time  | t <sub>off</sub>     | Duty $\leq$ 1%, t <sub>w</sub> = 10 $\mu$ s  | _   | 55   | _   |      |
| Total gate charge            |                | Qg                   |  |     | 11   |     |      |
| Gate-source charge           |                | Q <sub>gs</sub>      | $V_{DD} \approx 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$   |     | 6    | —   | nC   |
| Gate-drain charge            |                | Q <sub>gd</sub>      | ]  |     | 5    | —   |      |

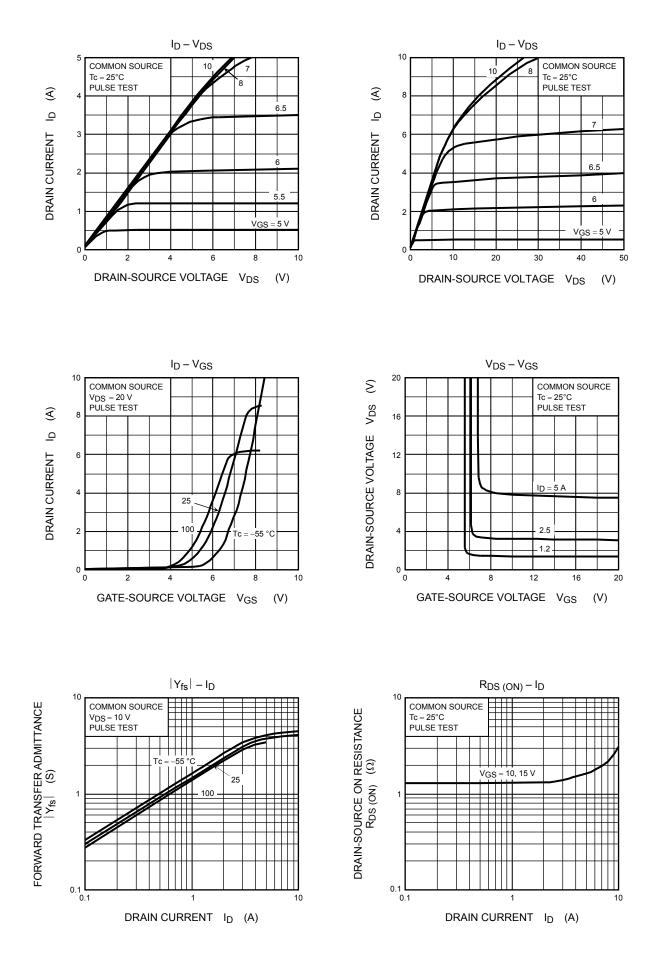
### Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics                           | Symbol           | Test Condition                                | Min | Тур. | Max  | Unit |
|---|------------------|---|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I <sub>DR</sub>  | —   | _   | _    | 5    | А    |
| Pulse drain reverse current (Note 1)      | I <sub>DRP</sub> | —   | _   | _    | 20   | А    |
| Forward voltage (diode)                   | V <sub>DSF</sub> | $I_{DR} = 5 \text{ A}, V_{GS} = 0 \text{ V}$  | _   | _    | -1.7 | V    |
| Reverse recovery time                     | t <sub>rr</sub>  | $I_{DR} = 5 \text{ A}, V_{GS} = 0 \text{ V},$ | _   | 1000 | _    | ns   |
| Reverse recovery charge                   | Q <sub>rr</sub>  | dl <sub>DR</sub> /dt = 100 A/μs               | _   | 5.0  | _    | μC   |

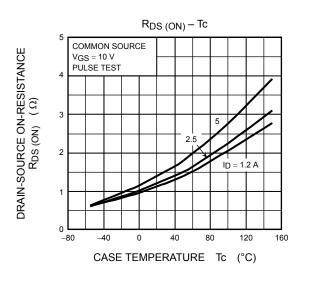
### Marking

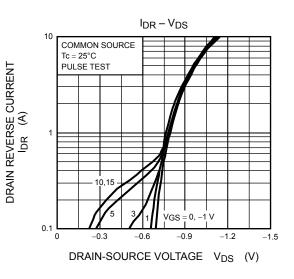


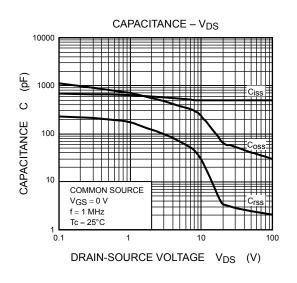
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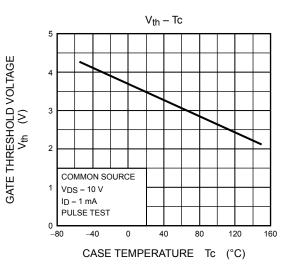
10

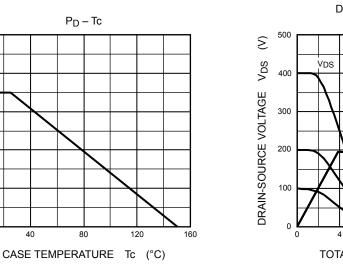
0

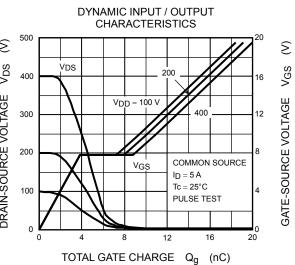
0

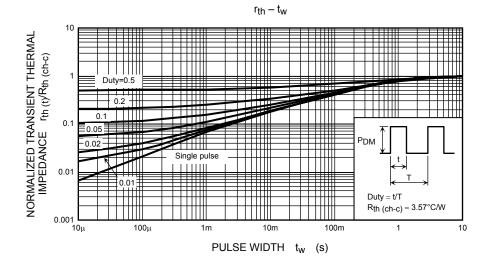
DRAIN POWER DISSIPATION PD (W)

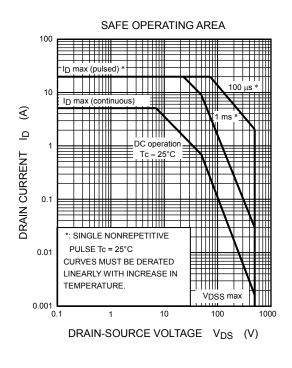
G 20

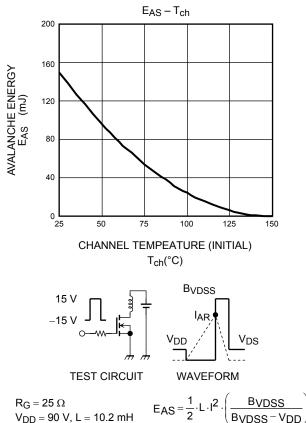












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